

L Number	Hits	Search Text	DB	Time stamp
1	8	((impurity adj concentration) or (well adj density)) same (threshold adj voltage) same (lower or higher or different)) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT	2003/11/13 14:43
2	4	((well near4 (density or concentration or impurity)) same (threshold adj voltage) same (lower or higher or different)) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 14:45
-	101	((power adj (supply or source)) or voltage) with (lower or higher or different)) same (power adj consumption) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/04 12:27
-	6	((lower near4 (voltage or power)) with (thinner near6 (oxide or gate or layer))) or ((higher near4 (voltage or power)) with (thicker near6 (oxide or gate or layer))) and @ad<=19981124) and 250/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/04 15:31
-	2	((higher adj voltage) same (thicker adj (oxide or layer))) and @ad<=19981124) and (camera or (image adj sensing))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/04 15:37
-	1	((lower adj voltage) same (thinner adj (oxide or layer))) and (camera or (image adj sensing)) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/04 15:39
-	22	((level adj shift\$3) same (CCD or imager or sensor) same (processing)) and @ad<=19981124) and (348/\$.ccls. or 250/\$.ccls.)	USPAT	2003/11/13 09:37
-	1	((charge with voltage with conversion) same switch) and (luminance same chrominance)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 10:10
-	69	((charge with voltage with conversion) same switch same (pixel or photodiode or photodetector or CCD or sensor)) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 10:12
-	7	(charge with voltage with conversion) same (transfer near5 switch) same (pixel or photodiode or photodetector or CCD or sensor) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 10:15
-	20	((higher or lower) with (threshold adj voltage)) same ((power adj (supply or source)) with (higher or lower))) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 10:44
-	13	((higher or lower) adj voltage) same ((thicker or thinner) adj (oxide or layer or gate))) and @ad<=19981124) and (CCD or sensor or pixel or imager)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 11:06
-	17	((higher or lower) adj voltage) or ((thicker or thinner) adj (oxide or layer or gate))) same ((higher or lower) adj threshold)) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 11:05
-	34	((thicker or thinner) adj (oxide or layer or gate)) same ((higher or lower) adj threshold adj voltage)) and @ad<=19981124	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/13 11:07
-	8	((impurity adj concentration) or (well adj density)) same (threshold adj voltage) same (lower or higher)) and (348/\$.ccls. or 250/\$.ccls.) and @ad<=19981124	USPAT	2003/11/13 14:25